

DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

QUICK REFERENCE DATA

Triode section

Anode current	I _a	1.5 mA
Transconductance	S	1.65 mA/V
Amplification factor	μ	70 -

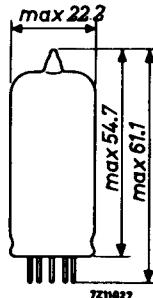
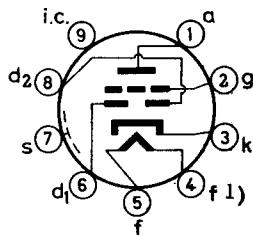
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I _f	100 mA
Heater voltage	V _f	14 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval



¹⁾ Earthed side of the heater circuit.

CAPACITANCESTriode section

Grid to all except anode	$C_{g(a)}$	2.3	pF
Anode to all except grid	$C_{a(g)}$	2.3	pF
Anode to grid	C_{ag}	1.2	pF
Grid to heater	C_{gf}	max.	0.05 pF

Diode sections

Diode No. 1 to all	C_{d_1}	0.9	pF
Diode No. 2 to all	C_{d_2}	0.9	pF
Diode No. 1 to diode No. 2	$C_{d_1d_2}$	max.	0.2 pF
Diode No. 1 to heater	C_{d_1f}	max.	0.25 pF
Diode No. 2 to heater	C_{d_2f}	max.	0.05 pF

Between triode and diode sections

Diode No. 1 to grid	C_{d_1g}	max.	0.007 pF
Diode No. 2 to grid	C_{d_2g}	max.	0.007 pF
Diode No. 1 to anode	C_{d_1a}	max.	0.005 pF
Diode No. 2 to anode	C_{d_2a}	max.	0.01 pF

TYPICAL CHARACTERISTICS OF THE TRIODE SECTION

Anode voltage	V_a	170	100	V
Grid voltage	V_g	-1.55	-1.0	V
Anode current	I_a	1.5	0.8	mA
Transconductance	S	1.65	1.4	mA/V
Amplification factor	μ	70	70	-
Internal resistance	R_i	42	50	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier, circuit Fig.1

Supply voltage	V_b	170	100	170	100	V
Anode resistor	R_a	0.22	0.22	0.1	0.1	MΩ
Cathode resistor	R_k	5.6	5.6	3.9	3.9	kΩ
Grid resistor	R_g	1.0	1.0	1.0	1.0	MΩ
Grid resistor next stage	R_g'	0.68	0.68	0.33	0.33	MΩ
Anode current	I_a	0.28	0.18	0.45	0.28	mA
Voltage gain	V_o/V_i	44	41	37	34	
Distortion at:						
output voltage $V_o = 3$ V RMS	d_t	1.1	1.4	1.1	2.0	%
output voltage $V_o = 5$ V RMS	d_t	1.3	1.9	1.7	3.5	%
output voltage $V_o = 8$ V RMS	d_t	1.85	-	2.6	-	%

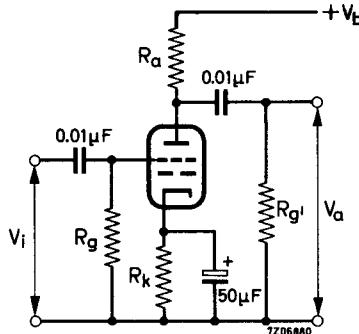
Supply voltage	V_b	170	100	170	100	V
Anode resistor	R_a	0.22	0.22	0.1	0.1	MΩ
Cathode resistor	R_k	0	0	0	0	Ω
Grid resistor	R_g	22	22	22	22	MΩ
Grid resistor next stage	R_g'	0.68	0.68	0.33	0.33	MΩ
Anode current	I_a	0.46	0.21	0.82	0.35	mA
Voltage gain	V_o/V_i	48	41	42	35	
Distortion at						
output voltage $V_o = 3$ V RMS	d_t	0.95	1.45	0.75	1.6	%
output voltage $V_o = 5$ V RMS	d_t	1.1	2.0	1.0	2.8	%
output voltage $V_o = 8$ V RMS	d_t	1.3	-	1.2	-	%

OPERATING CHARACTERISTICS (continued)

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube.

Fig.1

**LIMITING VALUES** (Design centre rating system)Triode section

Anode voltage	V _{a0}	max. 550 V
	V _a	max. 250 V
Anode dissipation	W _a	max. 0.5 W
Cathode current	I _k	max. 5 mA
Grid resistor	R _g	max. 3 MΩ
Cathode to heater voltage	V _{kf}	max. 100 V

Diode sections (each diode)

Diode voltage, negative peak	-V _{dp}	max. 350 V
Diode current:		
average	I _d	max. 0.8 mA
peak	I _{dp}	max. 5 mA
Cathode to heater voltage	V _{kf}	max. 100 V

PHILIPS

Data handbook



**Electronic
components
and materials**

UBC81

page	sheet	date
1	1	1970.01
2	2	1970.01
3	3	1970.01
4	4	1970.01
5	FP	1999.07.29